

Main Injector Upgrade R&D Collaboration on Electron Cloud Effects: Comparing the RF frequency of 53 MHz vs. 212 MHz*

M. A. Furman[†]

Center for Beam Physics

Lawrence Berkeley National Laboratory, Bldg. 71R0259

1 Cyclotron Rd.

Berkeley, CA 94720-8211

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We compare, by means of simulations, the electron-cloud build-up for the Fermilab Main Injector (MI) for the present RF frequency $f_{\text{RF}} = 53$ MHz vs. a hypothetical RF frequency $f_{\text{RF}} = 212$ MHz at a given total beam population N_{tot} . For simplicity, we assume the fill pattern for either RF frequency to consist of a single train of filled buckets followed by a single abort gap. We study the average electron-cloud density and incident electron-wall flux vs. N_{tot} in the range $N_{\text{tot}} = (3.29 - 16.4) \times 10^{13}$, for three assumed values of the peak secondary emission yield, namely $\delta_{\text{max}} = 1.2, 1.3$ and 1.4 . The electron-cloud intensity shows a clear threshold behavior as a function of N_{tot} : when N_{tot} exceeds a value N_{th} , the average electron density rises strongly and roughly proportionally to $(N_{\text{tot}} - N_{\text{th}})$. The threshold N_{th} has a sensitive inverse dependence on δ_{max} . As expected, the simulated electron-cloud effect is weaker for the higher RF frequency: for a given δ_{max} , N_{th} is roughly a factor of 2 higher for $f_{\text{RF}} = 212$ MHz than for 53 MHz. If N_{tot} happens to lie above the threshold for $f_{\text{RF}} = 53$ MHz but below the threshold for 212 MHz, then the electron density in the latter case can be 4–5 orders of magnitude smaller than in the former. If N_{tot} is above the threshold for 212 MHz, then the electron density at this frequency is still lower than for 53 MHz, but only by a factor of a few.

I. ASSUMPTIONS.

For each f_{RF} we assume a fill pattern as follows:

$$f_{\text{RF}} = 53 \text{ MHz: } 548 \times \text{F} + 40 \times \text{E} \quad (1a)$$

$$f_{\text{RF}} = 212 \text{ MHz: } 2192 \times \text{F} + 160 \times \text{E} \quad (1b)$$

where “F” and “E” signify full and empty buckets, respectively.¹

In any given fill pattern all the bunches have the same particle population N_b . When carrying out comparisons of the two frequencies, we assume that N_b for $f_{\text{RF}} = 212$ MHz is 1/4 that of the value for $f_{\text{RF}} = 53$ MHz, so that N_{tot} is the same in both cases. The range of values explored for $f_{\text{RF}} = 53$ MHz is $N_b = (6 - 30) \times 10^{10}$, corresponding to $(1.5 - 7.5) \times 10^{10}$ for $f_{\text{RF}} = 212$ MHz, and to $N_{\text{tot}} = (3.29 - 16.4) \times 10^{13}$ for either case. We look only at injection energy ($E_b = 8.9$ GeV) and only at the location of the installed retarding-field analyzer (RFA). Concerning the RMS bunch length, we assume $\sigma_z = 0.75$ m for $f_{\text{RF}} = 53$ MHz, and $\sigma_z = 0.75/4 = 0.1875$ m for $f_{\text{RF}} = 212$ MHz. We assume that, at the RFA location, the pipe is round with radius $a = 7.3$ cm and there is no magnetic field. We assume, for the purposes of parameter exploration, that the peak SEY δ_{max} is in the range 1.2–1.4, which is the probable range

for the actual MI chamber at the RFA location in its present state of conditioning [1, 2]. We use the stainless steel secondary emission model described in [3, 4], with the additional practical assumption that the SEY at 0 energy, $\delta(0)$, is proportional to δ_{max} .

When comparing the two RF frequencies, we only vary N_b and δ_{max} while keeping N_{tot} fixed. For each case, we simulate one full MI revolution and compute the one-turn average electron-wall incident electron flux, electron-cloud density, and other related quantities (the electron-cloud density reaches steady state in a fraction, typically 10-20%, of a revolution period).

We use an integration time step $\Delta t = 5 \times 10^{-11}$ s, a maximum of 20,000 macroelectrons allowed at any given time, and a 64×64 space-charge grid. Previous experience shows that, for the values of δ_{max} considered here, these parameter values are adequate to reach numerical convergence. CPU running time on a Macintosh G5 (1.8 GHz) is 1.5–2.5 hrs for one full MI revolution, depending on N_{tot} and δ_{max} . Ideally, we would simulate the electron-cloud build-up and decay during the full MI ramp, lasting ~ 0.5 s of accelerator time. Given that the revolution period is $\sim 11 \mu\text{s}$, this would amount to $\sim 45,000$ turns, clearly beyond present-day computer capabilities. Thus we only simulated the MI at injection energy, $E_b = 8.9$ GeV.

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[†]Electronic address: mafurman@lbl.gov; URL: <http://mafurman.lbl.gov>

¹ The actual values of f_{RF} are 52.809 and 211.24 MHz.

Parameters of the physical model and the simulation method are summarized in Tables I and II, which also define various other symbols used in this note.

TABLE I: Assumed MI fill pattern parameters for EC simulations.

Parameter	Symbol (unit)	Value	
RF frequency	f_{RF} (MHz)	52.809	211.24
Harmonic number	h	588	2352
No. of bunches	M	548	2192
Gap length	\dots (buckets)	40	160
Bunch spacing	\dots (buckets)	1	1
Bunch spacing	s_b (m)	5.645	1.411
Bunch spacing	t_b (ns)	18.94	4.734
Bunch population	N_b (10^{10})	6 – 30	1.5 – 7.5
RMS bunch length	σ_z (m)	0.75	0.1875
Total beam population	N_{tot} (10^{13})	3.29 – 16.4	

TABLE II: Other assumed MI parameters for EC simulations.

Parameter	Symbol (unit)	Value
Ring and beam parameters		
Ring circumference	C (m)	3319.419
Beam pipe cross section	\dots	round
Beam pipe radius	a (cm)	7.3
Beam energy	E_b (GeV)	8.9
Relativistic beam factor	γ_b	9.486
Revolution period	T_0 (μs)	11.13
Bunch profile	\dots	3D gaussian
Transverse RMS bunch sizes	(σ_x, σ_y) (mm)	(2.3, 2.8)
Parameters for primary e^- sources		
Residual gas pressure	P (nTorr)	20
Temperature	T (K)	305
Ionization cross-section	σ_i (Mbarns)	2
Ionization e^- creation rate	n'_e ($((e/p)/\text{m})$)	1.266×10^{-7}
Secondary e^- parameters		
Peak SEY	$\delta_{\text{max}} \equiv \delta(E_{\text{max}})$	1.2 – 1.4
Energy at peak SEY	E_{max} (eV)	292.6
SEY at 0 energy	$\delta(0)$	0.29 – 0.34
Simulation parameters		
Simulated section	\dots	field-free region
Length of simulated region	L (m)	0.1
(Full bunch length)/(RMS bunch length)	L_b/σ_z	5
No. primary macroelectrons/bunch	\dots	100
Max. no. of macroelectrons allowed	\dots	20000
No. kicks/bunch ($f_{\text{RF}} = 53$ MHz)	N_k	253
No. kicks/bunch ($f_{\text{RF}} = 212$ MHz)	N_k	65
Integration time step	Δt (s)	5×10^{-11}
Space-charge grid	\dots	64×64

II. RESULTS.

Fig. 1 shows the average incident electron flux J_e at the walls of the chamber (we checked that J_e on the RFA is essentially equal to the average of J_e over the entire chamber, despite the fact that the transverse beam shape is not round, but is rather upright with an aspect ratio $\sigma_x/\sigma_y = 2.3/2.8 \simeq 0.82$). For reference, the values of J_e in Fig. 1 might be compared with the measured RFA signal [5] for present-day fill patterns with $N_{\text{tot}} \simeq (3-4) \times 10^{13}$: from the RFA calibration and estimated acceptance one infers an incident flux in the range $J_e \simeq (0-10)$ mA/m² [1, 2], with 5 mA/m² being a typical peak value usually obtained at $E_b \sim 60$ GeV.

Figure 2 shows the average electron-cloud density vs. N_{tot} , along with the average beam neutralization density,

$$n_b = \frac{N_b}{\pi a^2 s_b} = \frac{N_{\text{tot}}}{\pi a^2 s_b M} \quad (2)$$

For sufficiently high δ_{max} and/or N_{tot} , the average electron-cloud density exceeds the beam neutralization level. This condition is a very rough indication of the onset of single-bunch instability or emittance growth. A more direct indicator is the neutralization density within the 1- σ beam ellipse, which is much higher than the average value.

Figures 1 and 2 clearly exhibit a threshold behavior in N_{tot} . When N_{tot} exceeds a certain value N_{th} , the average electron-cloud density, to first approximation, grows like

$$n_e \simeq n_1(N_{\text{tot}} - N_{\text{th}}) \quad (3)$$

where $n_1 \simeq 0.04 \text{ m}^{-3}$, roughly independently of δ_{max} and f_{RF} . On the other hand, as shown in Fig. 3, the threshold N_{th} does depend on both δ_{max} and f_{RF} , in the form

$$N_{\text{th}} \simeq -N_1(\delta_{\text{max}} - \delta_1) \quad (4)$$

where $N_1 \simeq 2.5 \times 10^{14}$, roughly independently of f_{RF} , and

$$\delta_1 \simeq \begin{cases} 1.75, & f_{\text{RF}} = 53 \text{ MHz} \\ 1.55, & f_{\text{RF}} = 212 \text{ MHz} \end{cases} \quad (5)$$

The growth of n_e and J_e as a function of N_{tot} can be partially explained by the monotonic dependence of the electron-wall impact energy E_0 on N_{tot} , as shown in Fig. 4. As E_0 increases towards the energy $E_{\text{max}} \simeq 293$ eV where the SEY $\delta(E_0)$ has a peak, one naturally expects an increase in the effective SEY, hence a larger n_e . This argument, however, does not explain the above-mentioned threshold behavior, which probably involves a

combination of secondary emission, space-charge forces, and the partial absorption of low-energy electrons striking the walls.

III. CONCLUSIONS.

The main results of our investigation are: (1) the electron-cloud intensity shows a clear threshold behavior as a function of N_{tot} : when N_{tot} exceeds a value N_{th} , the average electron-cloud density rises proportionally to $(N_{\text{tot}} - N_{\text{th}})$. (2) The threshold N_{th} has a sensitive inverse dependence on δ_{max} , and a sensitive direct dependence on f_{RF} : for a given δ_{max} , N_{th} is roughly a factor of 2 higher for $f_{\text{RF}} = 212$ MHz than for 53 MHz. For fixed N_{tot} , this qualitative beneficial effect of the higher f_{RF} can be expected on rather simple grounds, because the correspondingly lower value of N_b makes the electron-wall impacts less energetic hence less effective in generating secondary electrons.

The dependence of N_{th} on f_{RF} affords the possibility of dramatically reducing the electron-cloud density assuming one has some freedom to choose the value of N_{tot} . This is because there is always a range of N_{tot} for which the electron cloud is below threshold for $f_{\text{RF}} = 212$ MHz but above threshold for $f_{\text{RF}} = 53$ MHz. For example, in Fig. 2 (bottom) for the case $\delta_{\text{max}} = 1.3$ and $N_{\text{tot}} = 0.8 \times 10^{14}$, the simulated electron-cloud density n_e is almost 5 orders of magnitude smaller for $f_{\text{RF}} = 212$ MHz than for 53 MHz. On the other hand, if N_{tot} is so high that it is above threshold for $f_{\text{RF}} = 212$ MHz (and, *a fortiori*, for 53 MHz), then the beneficial effect of the higher f_{RF} on the density is in the range of a factor of a few rather than several orders of magnitude.

Although the exercise carried out here is based on a simplified beam fill pattern, we expect the qualitative features of our results to remain valid for more complicated patterns, involving several gaps in the bunch train, provided the values of N_{tot} are in the range considered here.

This investigation does not address the effects of the electron cloud on the beam, which remain to be investigated separately.

Acknowledgments

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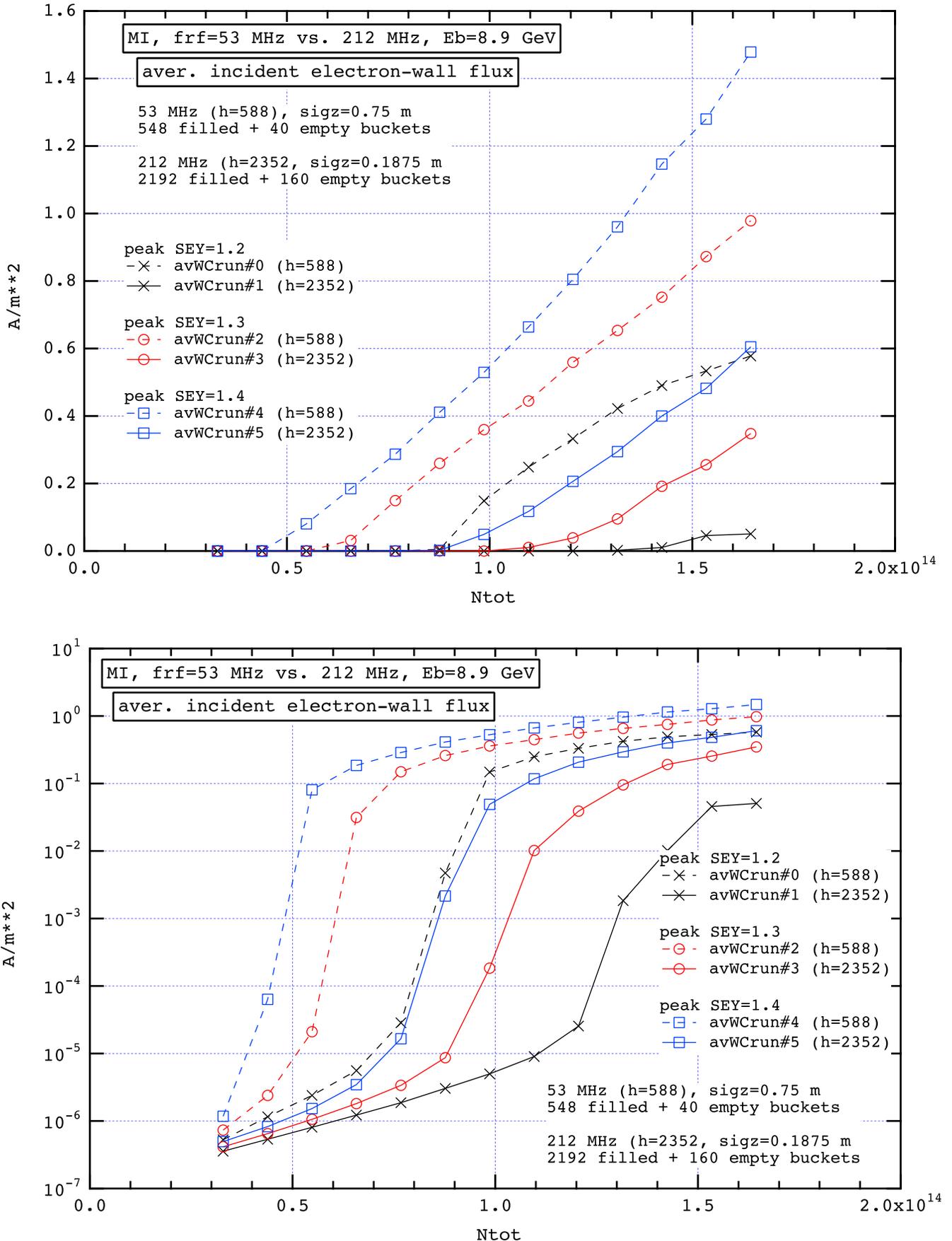
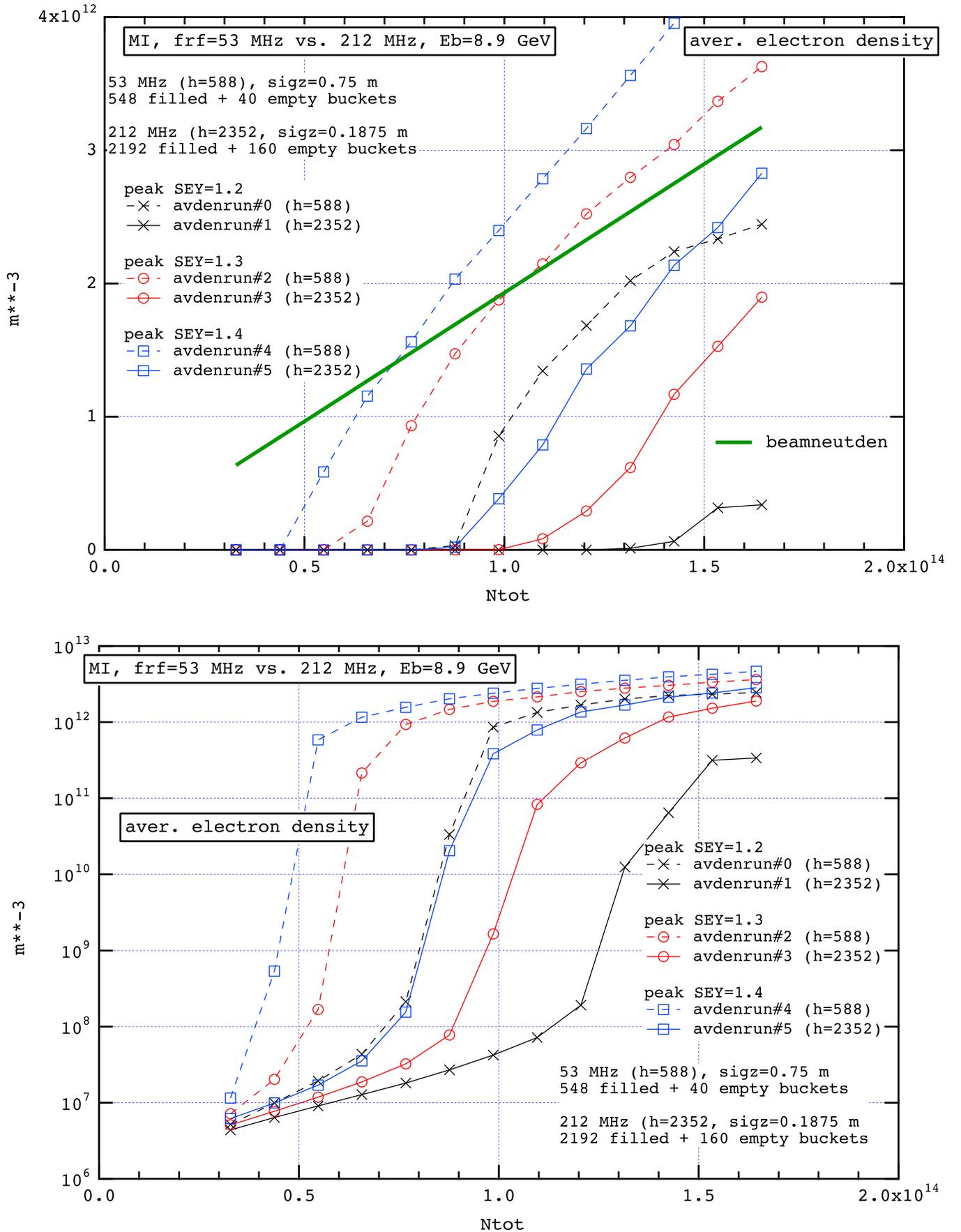


FIG. 1: Average simulated incident electron flux at the vacuum chamber walls. Top: linear scale; bottom: log scale (same data).



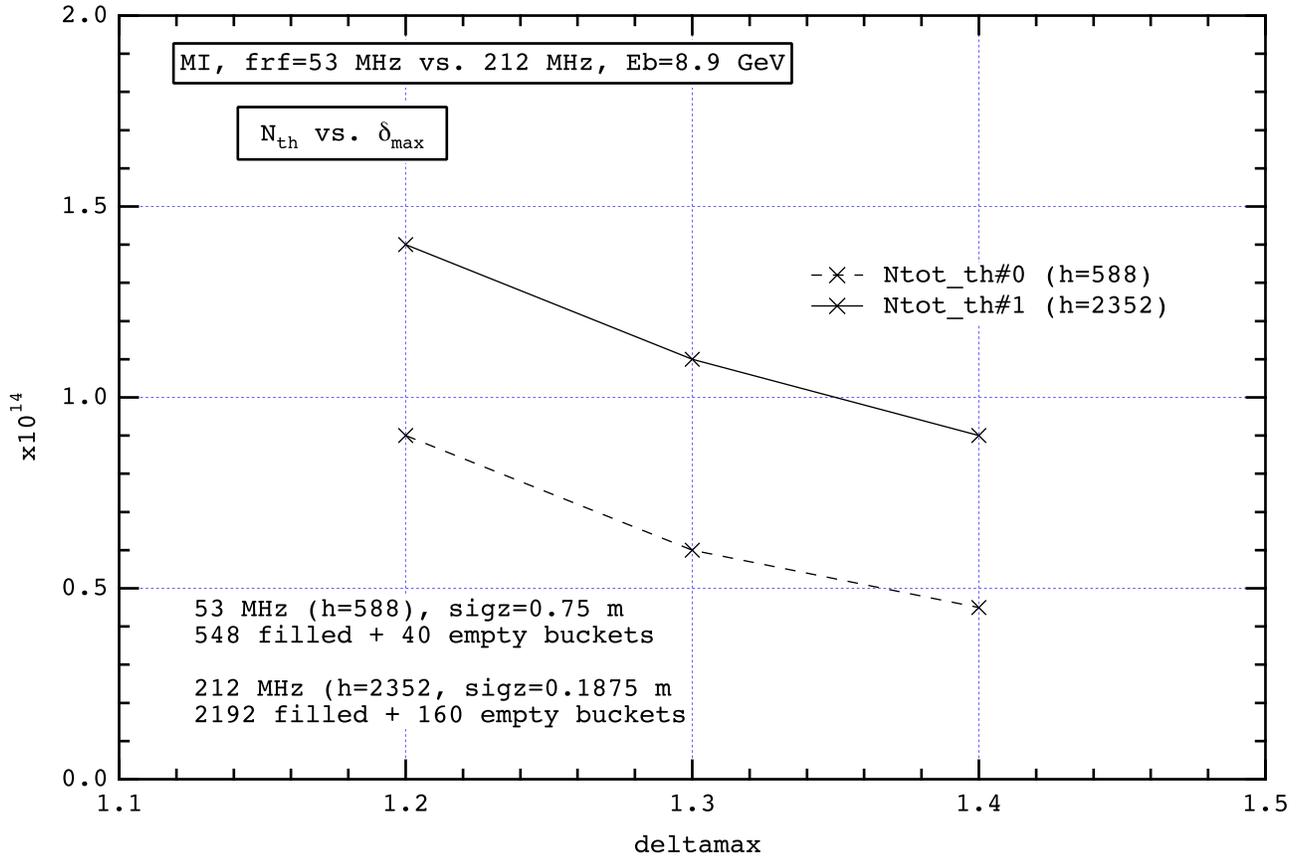


FIG. 3: N_{th} vs. δ_{max} (Eqs. (4-5)).

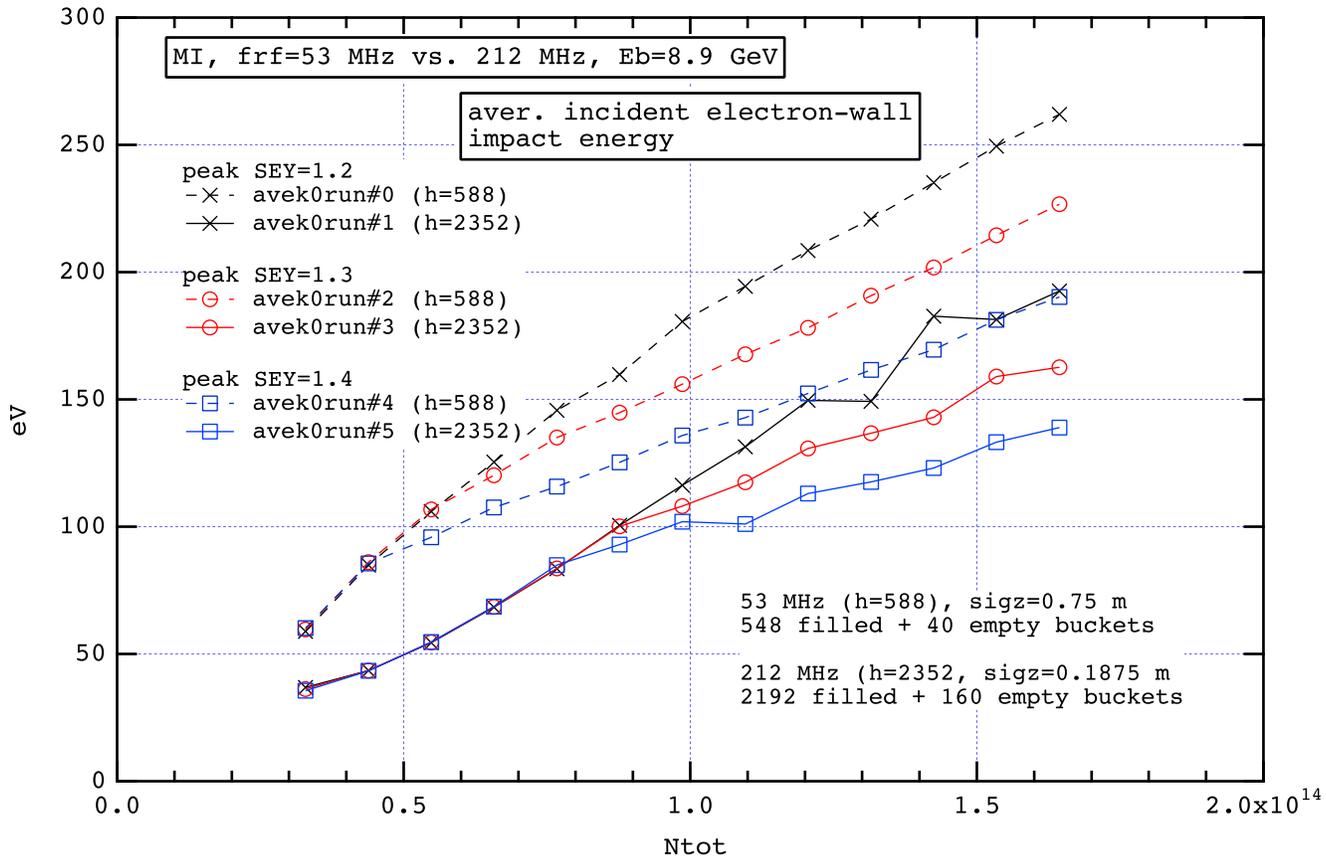


FIG. 4: Average simulated impact kinetic energy at the walls, per electron-wall collision.